

ANALOG Low Noise Micropower
 Precision Voltage References

ADR290/ADR291/ADR292

8

5

PIN 3

VOUT

PIN CONFIGURATIONS 8- Lead Narrow Body SO (R Suffix)

1

4 GND

PIN 1

VIN

FEATURES

Voltage Options 2.048 V, 2.500 V and 4.096 V 2.7 V to 15 V Supply Range Supply Current 12 µA max **Initial Accuracy** ± 2 **mV max Temperature Coefficient 8 ppm/°C max Low -Noise 6** m**V p-p (0.1 – 10 Hz) High Output Current 5 mA min Temperature Range** 2**40**8**C to** 1**125**8**C REF02/ REF19x Pinout**

APPLICATIONS Portable Instrumentation Precision Reference for 3[/] V and (5 V Systems **A/ D and D/ A Converter Reference Solar Pow/ered Applications** Loop-Current-Row ered Instruments

GENERAL DESCRIPTION

The ADR290, ADR291 and ADR292 are low noise, micropower precision voltage references that use an XFET^W reference circuit. T he new XFET™ architecture offers significant performance improvements over traditional bandgap and Zenerbased references. Improvements include: one quarter the voltage noise output of bandgap references operating at the same current, very low and ultralinear temperature drift, low thermal hysteresis and excellent long-term stability. **TEMPLETION**
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 OBSOLET POWER BAD ADR29

The ADR29x family are series voltage references providing stable and accurate output voltages from supplies as low as 2.7 V. Output voltage options are 2.048 V, 2.5 V and 4.096 V for the ADR290, ADR291 and ADR292 respectively. Quiescent current is only 12 µA, making these devices ideal for battery powered instrumentation. T hree electrical grades are available offering initial output accuracies of ± 2 mV, ± 3 mV and ± 6 mV max for the ADR290 and ADR291 and ± 3 mV, ± 4 mV and ± 6 mV max for the ADR292. Temperature coefficients for the three grades are 8 ppm/°C, 15 ppm/°C and 25 ppm/°C max, respectively. Line regulation and load regulation are typically 30 ppm/V and 30 ppm/mA, maintaining the reference's overall high performance. For a device with 5.0 V output, refer to the ADR293 data sheet.

The ADR290, ADR291 and ADR292 references are specified over the extended industrial temperature range of –40°C to +125°C. Devices are available in the 8-lead SOIC, 8-lead T SSOP and the TO-92 package.

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3- Pin TO- 92 (T9 Suffix)

PIN 2 GND

BOTTOM VIEW

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ADR290–SPECIFICATIONS

Electrical Specifications (V_s = +2.7 V, T_A = +25°C unless otherwise noted)

Electrical Specifications (V^S = 1**2.7 V, TA =** 2**40**8**C** ≤ **T^A** ≤ 1**125**8**C unless otherwise noted)**

$_{\rm NOTE}$

Specifications subject to change without notice.

ADR291–SPECIFICATIONS

ADR290/ADR291/ADR292

Electrical Specifications (V_s = +3.0 V, T_A = +25°C unless otherwise noted)

Electrical Specifications ($V_s = +3.0$ V, $T_A = -40^{\circ}C \le T_A \le +125^{\circ}C$ unless otherwise noted)

NOTE

Specifications subject to change without notice.

ADR292–SPECIFICATIONS

Electrical Specifications (V_s = +5 V, T_A = +25°C unless otherwise noted)

$\textbf{Electrical Specifications}$ ($V_s = +5$ V, $T_A = -40^{\circ}\text{C} \leq T_A \leq +125^{\circ}\text{C}$ unless otherwise noted)

NOTE

Specifications subject to change without notice.

WAFER TEST LIMITS (@ I LOAD = 0 mA, TA = 1**25**8**C unless otherwise noted)**

XOTES
Electrica

lectrical tests are performed as wafer probe to the limits shown. Due to variations in assembly methods and normal yield loss, yield after packaging is not guaranteed
In standard product dice. Consul factory to negotiate s product dice. Consult factory to negotiate specifications based on dice lot qualification through sample lot assembly and testing.
Is subject to change without notice. Specifications subject to change with δ

For additional DICE ordering information, refer to databook.

ABSOLUTE MAXIMUM RATINGS*

Package Type θ_{JA}^1

 θ_{JC} **Units**

***CAUTION**

- 1. Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. T his is a stress rating only; functional operation at or above this specification is not implied. Exposure to the above maximum rating conditions for extended periods may affect device reliability.
- 2. Remove power before inserting or removing units from their sockets.
- 3. Ratings apply to both D ICE and packaged parts, unless otherwise noted

CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD R290/AD R291/AD R292 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. T herefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

Figure 2. ADR291 V_{OUT} vs. Temperature

Figure 3. ADR292 V_{OUT} vs. Temperature

Figure 4. ADR290 Quiescent Current vs. Input Voltage

Figure 5. ADR291 Quiescent Current vs. Input Voltage

Figure 6. ADR292 Quiescent Current vs. Input Voltage

Figure 8. ADR290/ADR291/ADR292 Line Regulation vs. **Temperature**

Figure 9. ADR290/ADR291/ADR292 Line Regulation vs. **Temperature**

Figure 11. ADR291 Minimum Input-Output Voltage Differential vs. Load Current

Figure 12. ADR292 Minimum Input-Output Voltage Differential vs. Load Current

Figure 14. ADR291 Load Regulation vs. Temperature

Figure 15. ADR292 Load Regulation vs. Temperature

Figure 16. ADR290 ΔV_{OUT} from Nominal vs. Load Current

Figure 17. ADR291 ΔV_{OUT} from Nominal vs. Load Current

Figure 18. ADR292 ΔV_{OUT} from Nominal vs. Load Current

Figure 20. ADR290/ADR291/ADR292 Ripple Rejection vs. **Frequency**

Figure 21. ADR290 0.1 Hz to 10 Hz Noise

Figure 23. ADR291 Output Impedance vs. Frequency

Figure 24. ADR292 Output Impedance vs. Frequency

Figure 26. ADR291 Load Transient

Figure 27. ADR291 Load Transient

THEORY OF OPERATION

The ADR29x series of references uses a new reference generation technique known as XFET™ (eXtra implanted junction FET). This technique yields a reference with low noise, low supply current and very low thermal hysteresis.

The core of the $XFET^{TM}$ reference consists of two junction fieldeffect transistors, one of which has an extra channel implant to raise its pinch-off voltage. By running the two JFET S at the same drain current, the difference in pinch-off voltage can be amplified and used to form a highly stable voltage reference. The intrinsic reference voltage is around 0.5 V with a negative temperature coefficient of about –120 ppm/K. T his slope is essentially locked to the dielectric constant of silicon and can be closely compensated by adding a correction term generated in the same fashion as the proportional-to-temperature (PT AT) term used to compensate bandgap references. The big advan- ϕ tage fover a bandgap reference is that the intrinsic temperature coefficient is some thirty rimes lower (therefore less correction is heeded) and this results in much lower/noise since most of the noise of a bandgap reference comes from the temperature compensation circuitry.

The simplified schematic below shows the basis topology of the ADR29x series. The temperature colvection term is provided by a current source with value designed to be proportional to absolute temperature. T he general equation is:

$$
V_{OUT} = \Delta V_P \left(\frac{R1 + R2 + R3}{R1}\right) + \left(I_{PTAT}\right)(R3)
$$

where ΔV_P is the difference in pinch-off voltage between the two FETs, and I_{PTAT} is the positive temperature coefficient correction current. T he various versions of the AD R29x family are created by on-chip adjustment of R1 and R3 to achieve 2.048 V, 2.500 V or 4.096 V at the reference output.

The process used for the XFET reference also features vertical NPN and PNP transistors, the latter of which are used as output devices to provide a very low drop-out voltage.

Figure 30. ADR290/ADR291/ADR292 Simplified Schematic

D evice Power D issipation Considerations

The ADR29x family of references is guaranteed to deliver load currents to 5 mA with an input voltage that ranges from 2.7 V to 15 V (minimum supply voltage depends on output voltage option). When these devices are used in applications with large input voltages, care should be exercised to avoid exceeding the published specifications for maximum power dissipation or junction temperature that could result in premature device failure. T he following formula should be used to calculate a device's maximum junction temperature or dissipation:

$$
P_D = \frac{T_{\rm J} - T_{\rm A}}{\theta_{\rm JA}}
$$

In this equation, T_J and T_A are the junction and ambient temperatures, respectively, P_D is the device power dissipation, and θ_{JA} is the device package thermal resistance.

Basic Voltage Reference Connections

References, in general, require a bypass capacitor connected from the V_{OUT} pin to the GND pin. The circuit in Figure 31 illustrates the basic configuration for the AD R29x family of references. Note that the decoupling capacitors are not required

Figure 31. Basic Voltage Reference Configuration

Noise Perform ance

The noise generated by the ADR29x family of references is typically less than 12 μ V p-p over the 0.1 Hz to 10 Hz band. Figure 21 shows the 0.1 Hz to 10 Hz noise of the ADR290 which is only 6 µV p-p. T he noise measurement is made with a bandpass filter made of a 2-pole high-pass filter with a corner frequency at 0.1 Hz and a 2-pole low-pass filter with a corner frequency at 10 Hz.

Turn- On Tim e

Upon application of power (cold start), the time required for the output voltage to reach its final value within a specified error band is defined as the turn-on settling time. T wo components normally associated with this are the time for the active circuits to settle, and the time for the thermal gradients on the chip to stabilize. Figure 28 shows the turn-on settling time for the ADR291.

APPLICATIONS SECTION

A Negative Precision Reference without Precision Resistors In many current-output CM OS D AC applications, where the output signal voltage must be of the same polarity as the reference voltage, it is often required to reconfigure a current-switching D AC into a voltage-switching D AC through the use of a 1.25 V reference, an op amp and a pair of resistors. Using a current-switching D AC directly requires the need for an additional operational amplifier at the output to reinvert the signal. A negative voltage reference is then desirable from the point that

an additional operational amplifier is not required for either reinversion (current-switching mode) or amplification (voltageswitching mode) of the D AC output voltage. In general, any positive voltage reference can be converted into a negative voltage reference through the use of an operational amplifier and a pair of matched resistors in an inverting configuration. T he disadvantage to that approach is that the largest single source of error in the circuit is the relative matching of the resistors used.

The circuit illustrated in Figure 32 avoids the need for tightly matched resistors with the use of an active integrator circuit. In this circuit, the output of the voltage reference provides the input drive for the integrator. T he integrator, to maintain circuit equilibrium adjusts its output to establish the proper relationship between the reference's V_{OUT} and GND. Thus, any negative output voltage desired can be chosen by simply substituting for the appropriate reference IC. One caveat with this approach \mathcal{L} hould be mentioned: although rail-to-rail output amplifiers work best in the application, these operational amplifiers require a finite amount (mV) of headroom when required to provide any load current. The choice for the circuit's negative supply should take this issue into account.

Figure 32. A Negative Precision Voltage Reference Uses No Precision Resistors

A Precision Current Source

Many times in low power applications, the need arises for a precision current source that can operate on low supply voltages. As shown in Figure 33, any one of the devices in the ADR29x family of references can be configured as a precision current source. T he circuit configuration illustrated is a floating current source with a grounded load. T he reference's output voltage is bootstrapped across R_{SET} , which sets the output current into the load. With this configuration, circuit precision is maintained for load currents in the range from the reference's supply current, typically 12 µA to approximately 5 mA.

Figure 33. A Precision Current Source

High Voltage Floating Current Source

The circuit of Figure 34 can be used to generate a floating current source with minimal self heating. T his particular configuration can operate on high supply voltages determined by the breakdown voltage of the N -channel JFET.

Kelvin Connections

In many portable instrumentation applications, where PC board cost and area go hand-in-hand, circuit interconnects are very often of dimensionally minimum width. T hese narrow lines can cause large voltage drops if the voltage reference is required to provide load currents to various functions. In fact, a circuit's interconnects can exhibit a typical line resistance of 0.45 mW/square (1 oz. Cu, for example). Force and sense connections also referred to as Kelvin connections, offer a convenient method of eliminating the effects of voltage drops in circuit wires. Load currents flowing through wiring resistance produce an error ($V_{ERROR} = R \times I_L$) at the load. However, the Kelvin connection of Figure 35, overcomes the problem by including the wiring resistance within the forcing loop of the op amp. Since the op amp senses the load voltage, op amp loop control forces the output to compensate for the wiring error and to produce the correct voltage at the load.

Figure 35. Advantage of Kelvin Connection

Low Power, Low Voltage Reference For D ata Converters The ADR29x family has a number of features that makes it ideally suited for use with AD and D/A converters. The low supply voltage required makes it possible to use the ADR29x with today's converters that run on β V supplies without having to add a higher supply voltage for the reference. The low quie cent current $(12 \mu\text{A} \text{mak})$ and low noise, tight temperature coefficient, combined with the high accuracy of the $ARR2/x$ makes it ideal for low power applications such as hand-held, battery operated equipment.

One such ADC for which the ADR291 is well suited is AD 7701. Figure 36 shows the ADR 291 used as the reference for this converter. The AD7701 is a 16-bit A/D converter with on-chip digital filtering intended for the measurement of wide dynamic range, low frequency signals such as those representing chemical, physical or biological processes. It contains a charge balancing (sigma-delta) ADC, calibration microcontroller with on-chip static RAM , a clock oscillator and a serial communications port.

This entire circuit runs on \pm 5 V supplies. The power dissipation of the AD 7701 is typically 25 mW and, when combined with the power dissipation of the ADR291 (60 μ W), the entire circuit still consumes about 25 mW.

Figure 36. Low Power, Low Voltage Supply Reference for the AD7701

Voltage Regulator For Portable Equipm ent

The ADR29x family of references is ideal for providing a stable, low cost and low power reference voltage in portable equipment power supplies. Figure 37 shows how the AD R290/AD R291/ AD R292 can be used in a voltage regulator that not only has low output noise (as compared to switch mode design) and low power, but also a very fast recovery after current surges. Some precautions should be taken in the selection of the output capacitors. Too high an ESR (Effective Series Resistance) could endanger the stability of the circuit. A solid tantalum capacitor, 16 V or higher, and an aluminum electrolytic capacitor, 10 V or higher, are recommended for C1 and C2, respectively. Also, the path from the ground side of C1 and C2 to the ground side of R1 should be kept as short as possible.

OUTLINE D IMENSIONS

D imensions shown in inches and (mm).

8- Lead Narrow Body SO (R Suffix)

